FAIRCHILD

SEMICONDUCTOR IM

BD242/A/B/C

Medium Power Linear and Switching Applications

Complement to BD241/A/B/C respectively



1.Base 2.Collector 3.Emitter

PNP Epitaxial Silicon Transistor

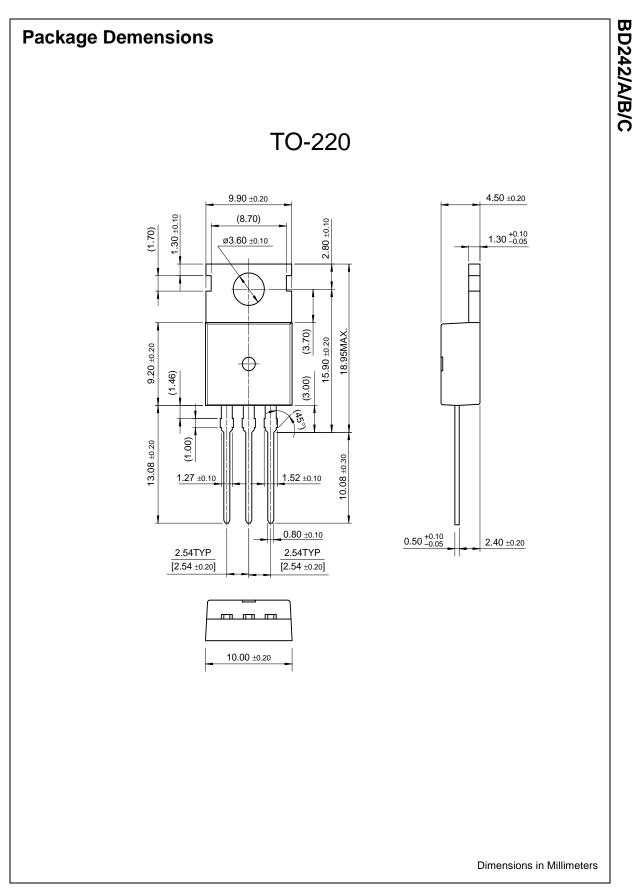
Absolute Maximum Ratings T_C=25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|------------------|--|------------|-------|
| V _{CEO} | Collector-Emitter Voltage | | |
| | : BD242 | - 45 | V |
| | : BD242A | - 60 | V |
| | : BD242B | - 80 | V |
| | : BD242C | - 100 | V |
| V _{CER} | Collector-Emitter Voltage | | |
| | : BD242 | - 55 | V |
| | : BD242A | - 70 | V |
| | : BD242B | - 90 | V |
| | : BD242C | - 115 | V |
| / _{EBO} | Emitter-Base Voltage | - 5 | V |
| С | Collector Current (DC) | - 3 | А |
| CP | *Collector Current (Pulse) | - 5 | А |
| В | Base Current | - 1 | А |
| °c | Collector Dissipation (T _C =25°C) | 40 | W |
| - J | Junction Temperature | 150 | °C |
| Г _{STG} | Storage Temperature | - 65 ~ 150 | °C |

Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|------------------------|--|--|-------|------|-------|-------|
| V _{CEO} (sus) | * Collector-Emitter Sustaining Voltage | | | | | |
| OLO() | : BD242 | $I_{\rm C} = -30$ mA, $I_{\rm B} = 0$ | - 45 | | | V |
| | : BD242A | ũ l | - 60 | | | V |
| | : BD242B | | - 80 | | | V |
| | : BD242C | | - 100 | | | V |
| I _{CEO} | Collector Cut-off Current : BD242/A | V _{CE} = - 30V, I _B = 0 | | | - 0.3 | mA |
| | : BD242B/C | $V_{CE} = -60V, I_B = 0$ | | | - 0.3 | mA |
| I _{CES} | Collector Cut-off Current : BD242 | V _{CE} = - 45V, V _{BE} = 0 | | | - 0.2 | mA |
| | : BD242A | $V_{CE} = -60V, V_{BE} = 0$ | | | - 0.2 | mA |
| | : BD242B | $V_{CE} = -80V, V_{BE} = 0$ | | | - 0.2 | mA |
| | : BD242C | $V_{CE} = -100V, V_{BE} = 0$ | | | - 0.2 | mA |
| EBO | Emitter Cut-off Current | $V_{EB} = -5V, I_{C} = 0$ | | | - 1 | mA |
| h _{FE} | * DC Current Gain | V _{CE} = - 4V, I _C = - 1A | 25 | | | |
| | | $V_{CE} = -4V, I_{C} = -3A$ | 10 | | | |
| V _{CE} (sat) | * Collector-Emitter Saturation Voltage | I _C = - 3A, I _B = - 0.6A | | | - 1.2 | V |
| V _{BE} (on) | * Base-Emitter ON Voltage | $V_{CE} = -4V, I_{C} = -3A$ | | | - 1.8 | V |

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|--------------------------|---------------------------|---|
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